

Maximum Ratings and Thermal Characteristics (T_A = 25 °C unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNITS | | |
|--|------------------|------------------|---------|------|--|
| Maximum Repetitive Peak Reverse Voltage | V _{RRM} | 200 | V | | |
| Maximum RMS Voltage | V _{RMS} | 140 | V | | |
| Maximum DC Blocking Voltage | | V _{DC} | 200 | V | |
| Maximum Average Forward Current | per device | | 16 | A | |
| | per diode | lf(AV) | 8 | | |
| Peak Forward Surge Current : 8.3 ms Single H Wave Superimposed On Rated Load Per Dioc | IFSM | 120 | A | | |
| Typical Junction Capacitance | | CJ | 00 | pF | |
| Measured at 1 MHZ And Applied $V_R = 4 V$ | | | 80 | | |
| Typical Thermal Resistance Per Diode | (Note 1) | Rejc | 6 | °C/W | |
| | (Note 1) | Rejl | 6.5 | | |
| Operating Junction Temperature Range | TJ | -55~175 | ٥C | | |
| Storage Temperature Range | | T _{STG} | -55~175 | ٥C | |



| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---------------------------|-----------------|---|------|-------|------|-------|
| Forward Voltage Per Diode | VF | I _F = 2 A, T _J = 25 °C | - | 0.77 | - | V |
| | | I _F = 4 A, T _J = 25 °C | - | 0.83 | - | V |
| | | I _F = 8 A, T _J = 25 °C | - | - | 0.95 | V |
| | | I _F = 2 A, T _J = 125 °C | - | 0.63 | - | V |
| | | I _F = 4 A, T _J = 125 °C | - | 0.7 | - | V |
| | | I _F = 8 A, T _J = 125 °C | - | 0.8 | - | V |
| Reverse Current Per Diode | I _R | $V_R = 160 V, T_J = 25 \circ C$ | - | 0.004 | - | uA |
| | | $V_R = 200 V, T_J = 25 \circ C$ | - | - | 1 | |
| | | $V_R = 200 V, T_J = 125 ^{\circ}C$ | - | - | 75 | |
| Reverse Recovery Time | T _{RR} | I _F = 0.5 A, I _R = 1 A, I _{RR} = 0.25 A, T _J = 25 °C | - | - | 35 | ns |
| Reverse Recovery Time | T _{RR} | I _F = 8 A, V _R = 200 V | - | 28 | - | ns |
| Peak Recovery Current | IRRM | di/dt = 300 A/uS | - | 6.5 | - | А |
| Reverse Recovery Charge | Q _{RR} | T _J = 25 °C | - | 96 | - | nC |
| Reverse Recovery Time | T _{RR} | I _F = 8 A, V _R = 200 V | - | 43 | - | ns |
| Peak Recovery Current | Irrm | di/dt = 300A/uS | - | 10 | - | А |
| Reverse Recovery Charge | QRR | T _J = 125 °C | - | 216 | - | nC |

NOTES :

1. Device mounted on a infinite heatsink.

MER1602FCT **TYPICAL CHARACTERISTIC CURVES** 1000 10 C_J, Junction Capacitance (pF) I_F, Forward Current (A) 8 100 6 4 10 2 per diode per diode 1 0 0 40 80 120 160 200 75 100 125 150 175 0 25 50 V_B, Reverse Bias Voltage (V) T_C, Case Temperature (°C) Fig.1 Forward Current Derating Curve **Fig.2 Typical Junction Capacitance** 100 100 T_J = 175°C per diode 01 10 10.0 10.0 10.0 10.0 10.0 10 T_J = 175°C I_F, Forward Current (A) 10 T_J = 150°C $T_{J} = 150^{\circ}C$ T₁ = 125°C 1 T_{.I} = 125°C T_{.J} = 100°C T_{.1} = 25°C = 100°C 0.1 T_J = 25°C ĥ. T_J = -55°C T_I = -55°C per diode 0.01 0.0001 0 0.6 0.3 0.9 1.2 1.5 20 40 60 80 100 Percent of Rated Reverse Voltage (%) V_F, Forward Voltage (V) **Fig.3 Typical Reverse Characteristics Fig.4 Typical Forward Characteristics** 100 1000 T_{RR} (nS) Q_{RR} (nC) 100

I_F=8A

10

50

V_R=200V

T_J = 125°C

100

per diode

250

300

200

di/dt (A/uS)

150

Fig.5 Typical Reverse Recovery Time Versus di/dt

PANJ

SEMI

10

50

I_F=8A

. V_R=200V

T_J = 125°C

100

150

Fig.6 Typical Reverse Recovery Charge Versus di/dt

200

di/dt (A/uS)

per diode

250

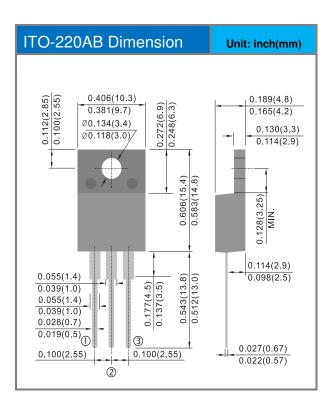
300



Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type | Marking | Version |
|-----------------------|--------------|--------------|------------|--------------------------------|
| MER1602FCT_T0_00601 | ITO-220AB | 50pcs / Tube | MER1602FCT | Halogen free RoHS compliant |

Packaging Information





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